

TS8021N - 50W CW, Broadband SPDT GaN RF Switch

1.0 Features

- Low insertion loss: 0.5dB @ 4GHz
- High isolation: 42dB @ 0.8GHz, 20dB @ 4GHz
- 50W CW, 125W Peak Power
- No external DC blocking capacitors on RF lines
- All RF ports OFF state
- Versatile 2.6-5.25V power supply
- Operating frequency: 30MHz to 4GHz

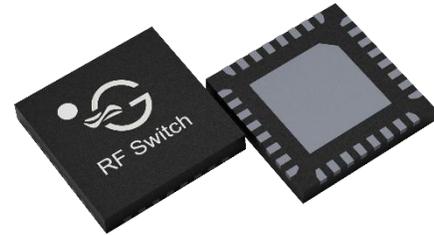


Figure 1 Device Image
(32 Pin 5.0x5.0x0.85mm³ QFN Package)

2.0 Applications

- Private mobile and military radios
- Public safety handsets
- Cellular infrastructure
- Small cells
- LTE relays and microcells
- Satellite terminals



RoHS/REACH/Halogen Free Compliance

3.0 Description

The TS8021N is a 2nd Generation symmetrical reflective Single Pole Dual Throw (SPDT) switch designed for broadband, high power switching applications. With a simple broadband match, the TS8021N can cover 30M to 4GHz bandwidth and provide low insertion loss, high isolation, and high linearity within a small package size. TS8021N is an excellent switch for all applications requiring low insertion loss, high isolation, and high linearity within a small package size.

The TS8021N is packaged into a compact Quad Flat No lead (QFN) 5x5mm 32 leads plastic package.

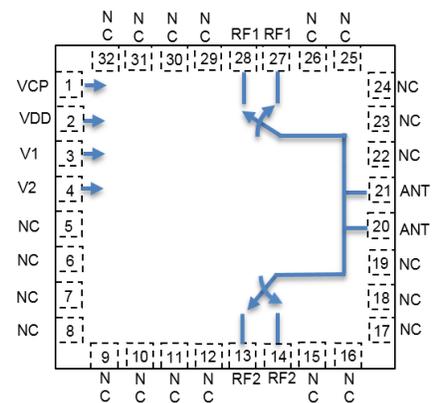


Figure 2 Function Block Diagram
(Top View)

4.0 Ordering Information

Table 1a Ordering Information

Device Part Number	Package Type	Notes
TS8021N	32 Pin 5.0x5.0x0.85mm ³ QFN	Core part number
TS8021N-EVB	Evaluation Board	
TS8021NMTRPBF	330mm reel, 3000pcs	Full reel

Table 1b Tape and Reel Information

Form	Quantity	Reel Diameter	Reel Width
Tape and Reel	3,000	13" (330mm)	18mm

5.0 Pin Description

Table 2 Pin Definition

Pin Number	Pin Name	Description
1	VCP	Internal charge pump voltage output. Connect a 1nF capacitor to GND on this pin to improve switching time.
2	VDD	DC power supply
3	V1	Switch control input 1
4	V2	Switch control input 2
5,6,7,8,9,10,11,16,17, 18,23,24,25,30,31,32	NC	No internal connection, can be grounded
12,15,19,22,26,29	NC	No internal connection. Do not connect to ground
13,14	RF2	RF port 2
20,21	ANT	Antenna port
27,28	RF1	RF port 1

Note: The backside ground (thermal) pad of the package must be grounded directly to the ground plane of PCB with multiple vias, and adequate heat sinking must be used to ensure proper operation and thermal management.

6.0 Absolute Maximum Ratings
Table 3 Absolute Maximum Ratings @T_A=+25°C Unless Otherwise Specified

Parameter	Symbol	Value	Unit
Electrical Ratings			
Power Supply Voltage	VDD	5.5	V
Storage Temperature Range	T _{st}	-55 to +125	°C
Operating Temperature Range	T _{op}	-40 to +85	°C
Maximum Junction Temperature	T _J	+140	°C
Maximum RF input power(400MHz~4000MHz)	RFx/ANT	47	dBm
Maximum RF input power(30MHz~400MHz)	RFx/ANT	46	dBm
Thermal Ratings			
Thermal Resistance (junction-to-case) – Bottom side	R _{θJC}	7.0	°C/W
Thermal Resistance (junction-to-top)	R _{θJT}	≤ 26	°C/W
Soldering Temperature	T _{SOLD}	260	°C
ESD Ratings			
Human Body Model (HBM)	Level 1B	500 to <1000	V
Charged Device Model (CDM)	Level C3	≥1000	V
Moisture Rating			
Moisture Sensitivity Level	MSL	1	-

Attention:

Maximum ratings are absolute ratings. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Exceeding one or a combination of the absolute maximum ratings may cause permanent and irreversible damage to the device and/or to surrounding circuit.

7.0 Electrical Specifications
Table 4 Electrical Specifications @T_A=+25°C Unless Otherwise Specified; VDD=+3.3V; 50Ω Source/Load.

Parameter	Condition	Minimum	Typical	Maximum	Unit
Operating frequency		30		4000	MHz
Insertion loss, RFx	800MHz		0.2	0.35	dB
	1.95GHz		0.3		
	4.0GHz		0.5		
Isolation ANT-RFx	800MHz	38	42		dB
	1.95GHz		32		
	4.0GHz		20		
Return loss ANT, RFx	800MHz		19		dB
	1.95GHz		16		
	4.0GHz		15		
Harmonic distortion					
H2	800MHz, Pin=45dBm		-86		dBc
H3	800MHz, Pin=45dBm		-89		dBc
IIP3	800MHz		71		dBm
P0.1dB ^[1]	800MHz, CW	47	50		dBm
P0.1dB ^[1]	30MHz, CW		46		dBm
Peak P0.1dB ^[1]	800MHz, 1% duty cycle, 1 mS period.		51		dBm
Switching time	50% ctrl to 10/90% of the RF value is settled. CP=1nF to ground on VCP pin.		5.2		μs
Control voltage	Power Supply VDD	2.6	3.3	5.25	V
	All control pins high, V _{ih}	1.0	3.3	5.25	V
	All control pins low, V _{il}	-0.3		0.5	V
Control current	All control pins low, I _{il}		0		μA
	All control pins high, I _{ih}			7.5	μA
Current consumption, I _{DD}	Active mode (VDD on)		160	200	μA

Note:

[1] P0.1dB is a figure of merit.

[2] No external DC blocking capacitors required on RF pins unless DC voltage is applied on a RF pin.

8.0 Switch Truth Table

Table 5 Switch Truth Table

V1	V2	Active RF Path
0	1	All OFF
0	0	ANT-RF1 ON
1	0	ANT-RF2 ON

Attention:

- [1] VDD should be applied first before V1 and V2, otherwise may cause damage to the device.
- [2] There are internal pull-downs to ground on both V1 and V2 control pins, the state at start-up without any control voltage applied will be ANT-RF1 ON.
- [3] If all OFF state is not used, the switch can be operated with single control pin V1.

9.0 Evaluation Board (matched)

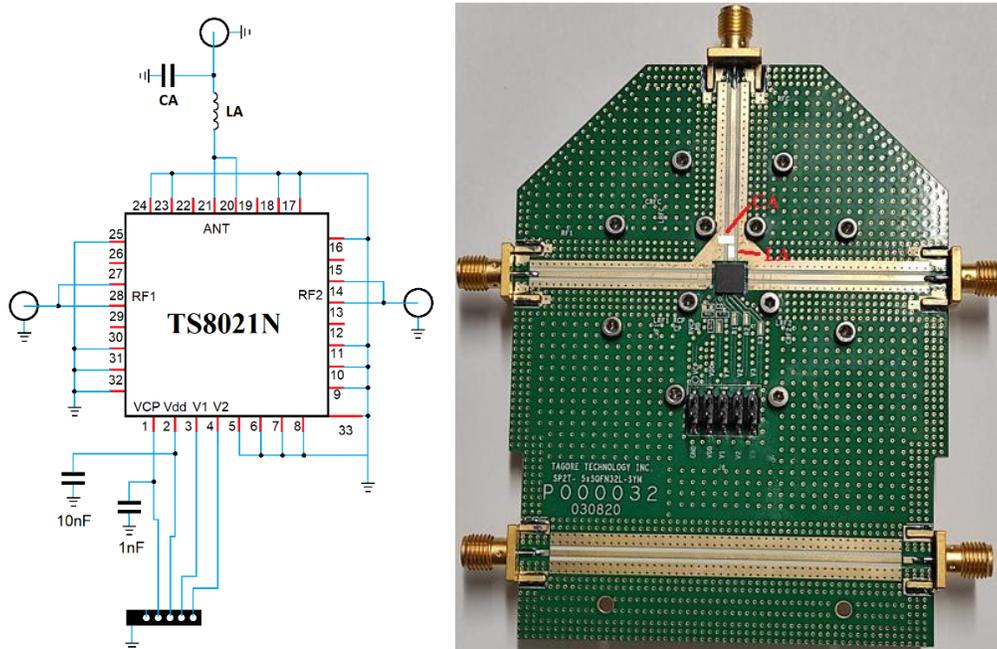


Figure 3 Evaluation Board and Schematic

Attention:

- [1] 33 refers to the center pad of the device. Multiple Plugged through hole vias should be added on this Ground Pad and adequate heat sinking should be used.
- [2] The purpose of connection between VCP and connector N1 is to monitor VCP, do not apply external voltage to VCP.
- [3] Place matching components close to pin of the part.

Table 6 Recommended Evaluation Board Component Values

Reference Designator	Value	Part #	Manufacturer
LA	0.8nH	0402DC-N80XJRU	Coilcraft
CA	0.5pF	0603	

10.0 Typical Characteristics

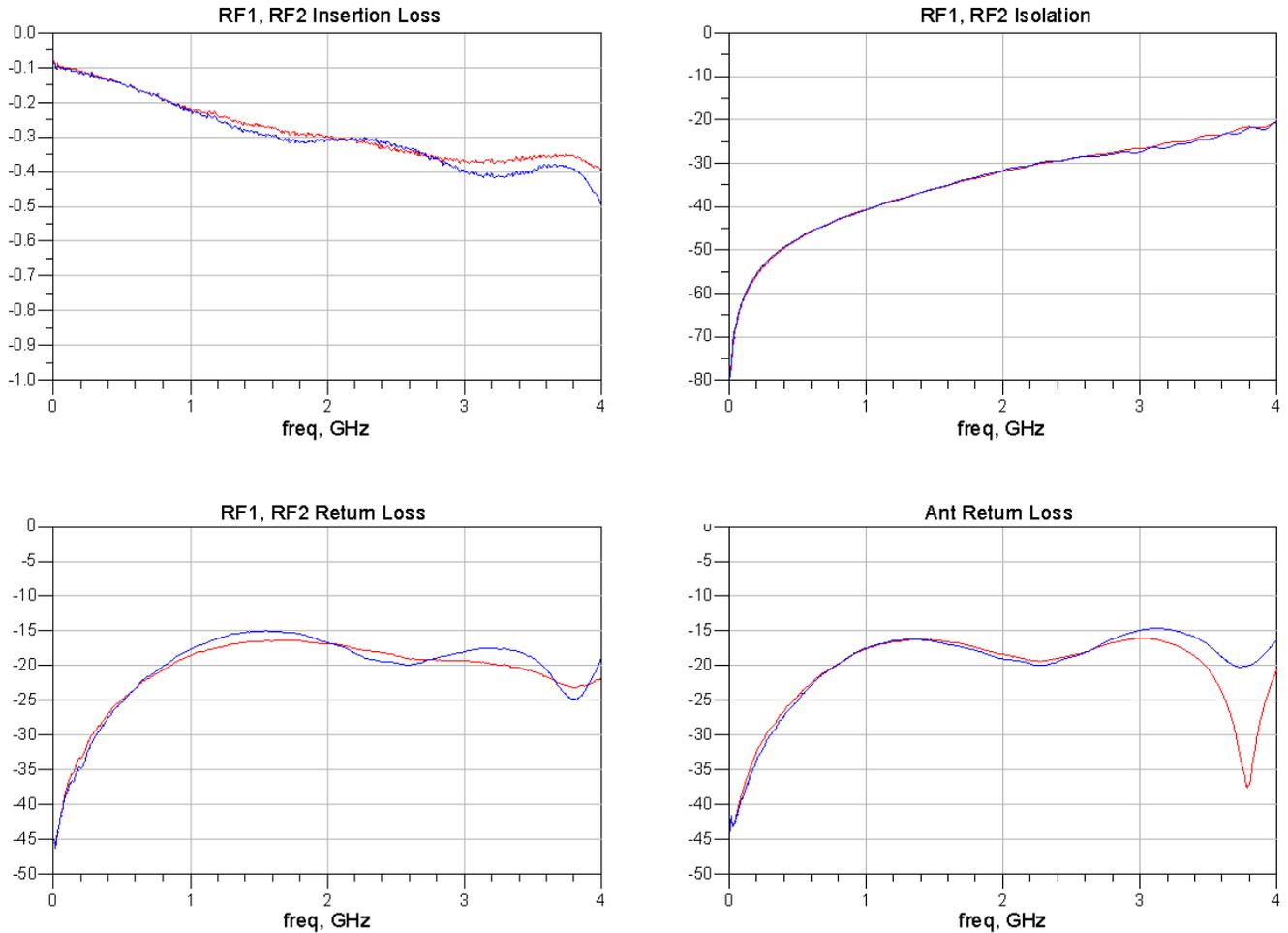


Figure 4 Evaluation Board Typical Characteristics (Matched)

11.0 Device Package Information

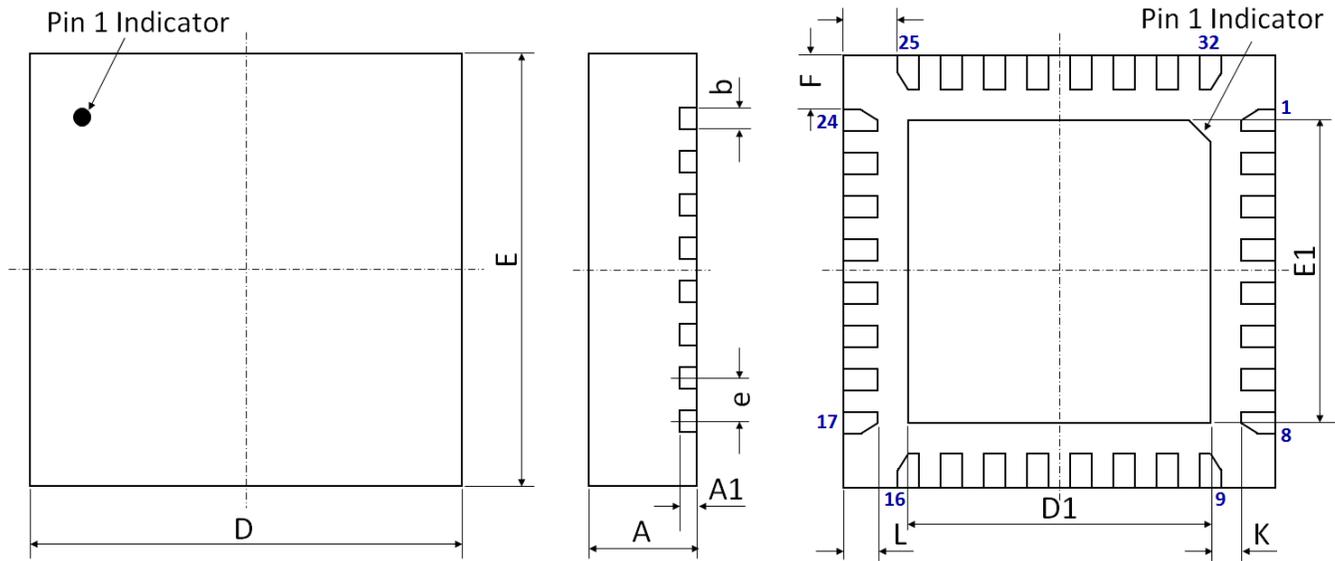


Figure 5 Device Package Drawing
(All dimensions are in mm)

Table 7 Device Package Dimensions

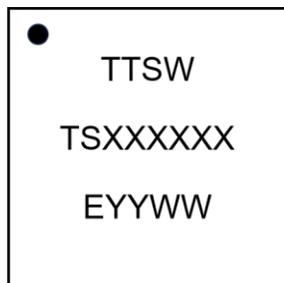
Dimension (mm)	Value (mm)	Tolerance (mm)	Dimension (mm)	Value (mm)	Tolerance (mm)
A	0.85	±0.05	E	5.00 BSC	±0.05
A1	0.203	±0.02	E1	3.10	±0.06
b	0.25	+0.05/-0.07	F	0.625	±0.05
D	5.00 BSC	±0.05	G	0.625	±0.05
D1	3.10	±0.06	L	0.40	±0.05
e	0.50 BSC	±0.05	K	0.50	±0.05

Note: Lead finish: Pure Sn without underlayer; Thickness: 7.5µm ~ 20µm (Typical 10µm ~ 12µm)

Attention:

Please refer to application notes [TN-001](#) and [TN-003](#) at <http://www.tagoretech.com> for PCB and soldering related guidelines.

Top-marking specification:



- = Pin 1 indicator
- TTSW = Tagore Technology SWitch
- TSXXXXXX = Part number (8 digits max)
- E = A fixed letter before the date code
- YY = Last two digits of assembly year
- WW = Assembly work week

12.0 PCB Land Design

Guidelines:

- [1] 4-layer PCB is recommended.
- [2] Via diameter is recommended to be 0.2mm to prevent solder wicking inside the vias.
- [3] Thermal vias shall only be placed on the center pad.
- [4] The maximum via number for the center pad is $5(X) \times 5(Y) = 25$.

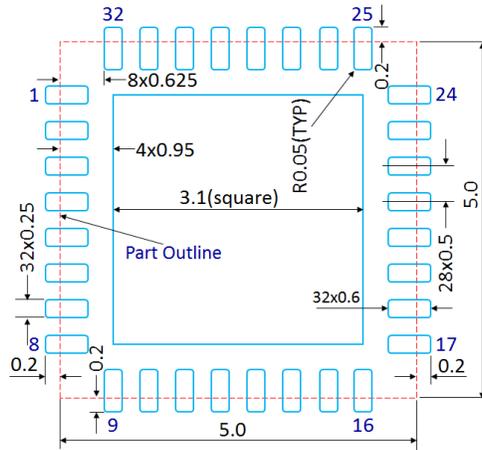


Figure 6 PCB Land Pattern
(Dimensions are in mm)

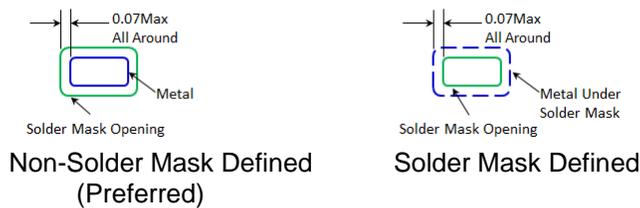


Figure 7 Solder Mask Pattern
(Dimensions are in mm)

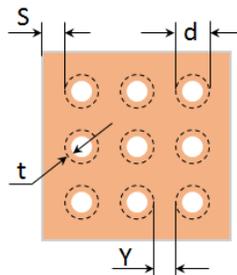


Figure 8 Thermal Via Pattern
(Recommended Values: $S \geq 0.15\text{mm}$; $Y \geq 0.20\text{mm}$; $d = 0.2\text{mm}$; Plating Thickness $t = 25\mu\text{m}$ or $50\mu\text{m}$)

14.0 Tape and Reel Information

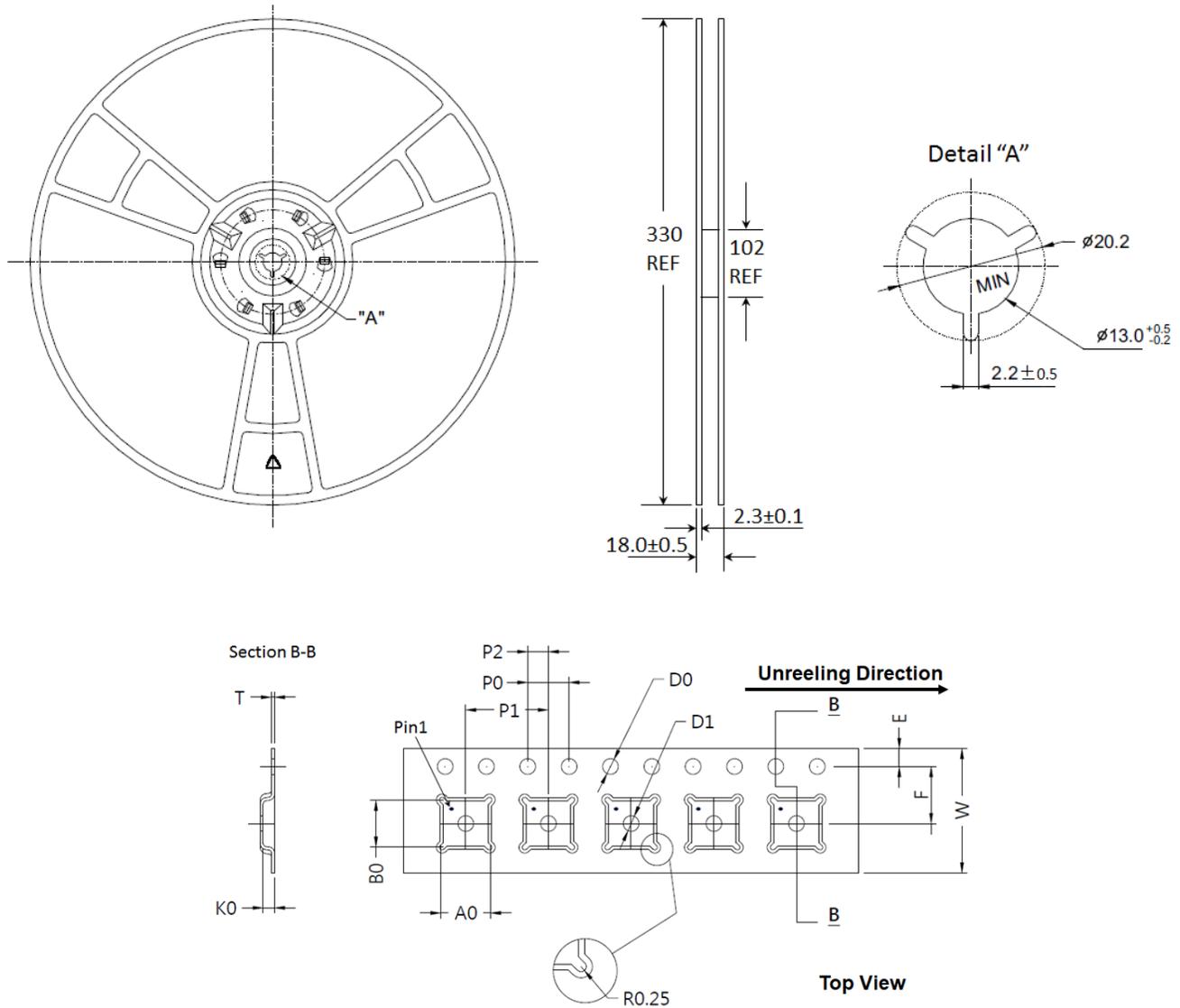


Figure 11 Tape and Reel Drawing

Table 8 Tape and Reel Dimensions

Dimension (mm)	Value (mm)	Tolerance (mm)	Dimension (mm)	Value (mm)	Tolerance (mm)
A0	5.25	±0.10	K0	1.10	±0.10
B0	5.25	±0.10	P0	4.00	±0.10
D0	1.50	+0.10/-0.00	P1	8.00	±0.10
D1	1.50	+0.10/-0.00	P2	2.00	±0.05
E	1.75	±0.10	T	0.30	±0.05
F	5.50	±0.05	W	12.00	±0.30

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